

# TPSCo 65nm – Limits of Spatial Resolution

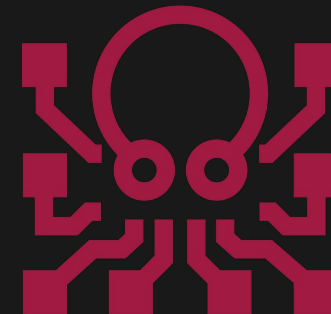
How Much Charge Information Do We Need?

Finn King on behalf of the OCTOPUS project

4<sup>th</sup> DRD3 week on Solid State Detectors R&D

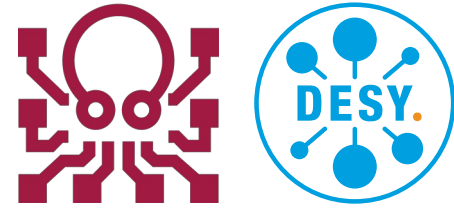
Geneva

11th November 2025



# The Question

## To Motivate the Design of a Pixel Sensor for a Future Lepton Collider

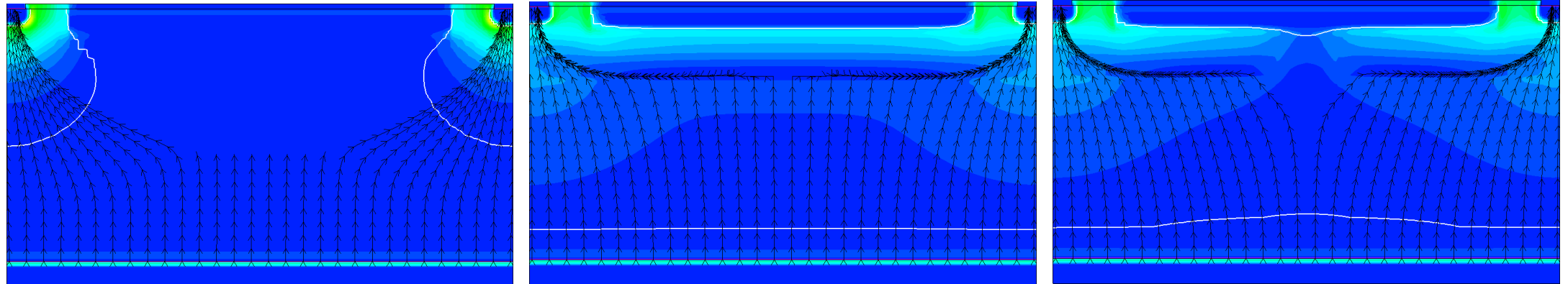
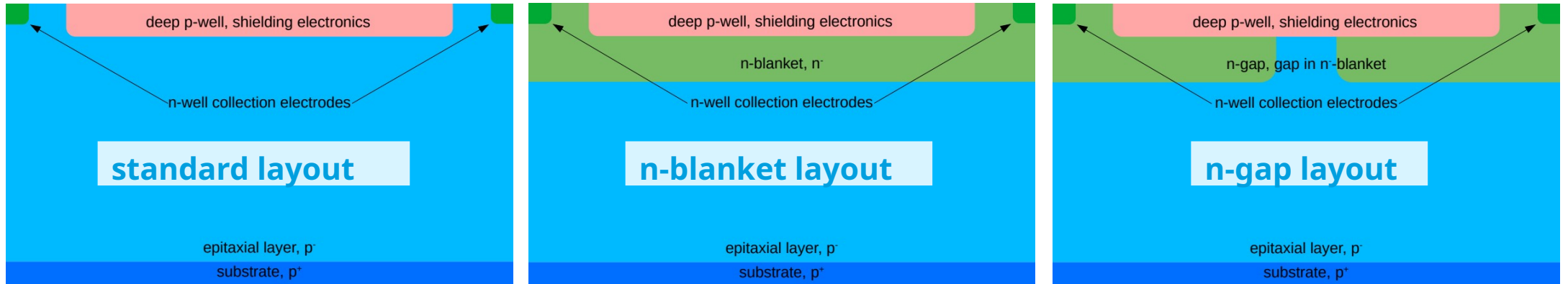
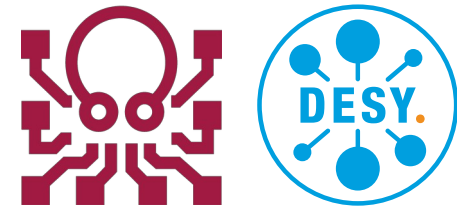


Key questions concerning spatial resolution

- What are the limits achievable with a certain design (standard, n-blanket, n-gap)?
- How do these limits depend on the pixel pitch and threshold?
- What is the potential for improvements that charge information offers?
  - How many bits do we need in order to leverage this potential?
  - What about two thresholds?

# Introducing Process Modifications

## The Trade-Off Between Charge Collection and Spatial Resolution



charge collection, detection efficiency

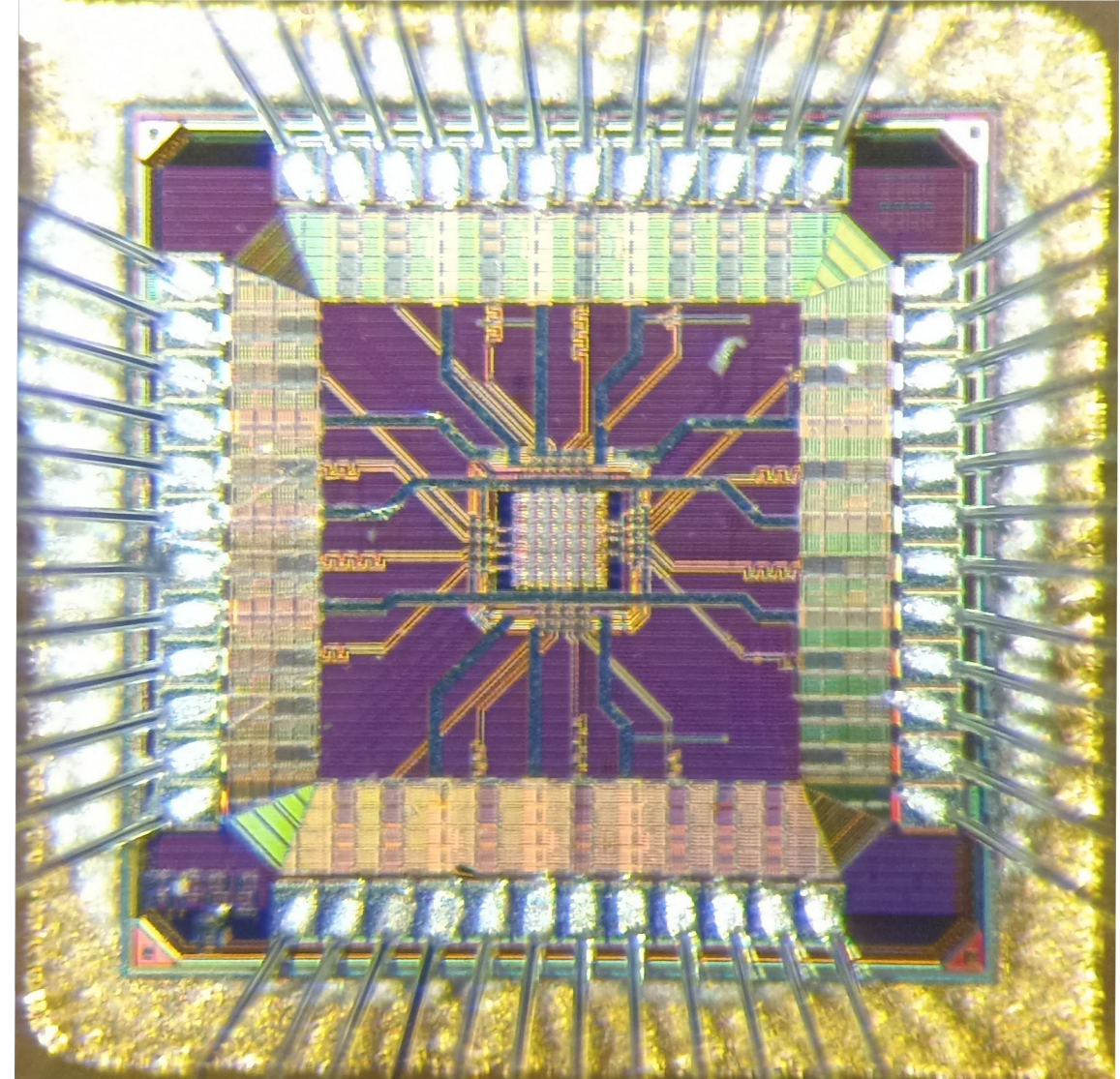
cluster size, spatial resolution

differences reinforced with decreasing thickness, increasing pitch, and increasing threshold

# The Data

## Test-Beam Campaign at DESY with Analog Pixel Test Structures (APTS)

- Designed by ALICE as investigator for ITS3 [\[ref. pub.\]](#)
  - Three design flavors (standard, n-blanket, n-gap)
  - Pitch between 10  $\mu\text{m}$  and 25  $\mu\text{m}$
- Readout developed with CERN EP R&D using Caribou
  - “Analog” charge measurement, no online threshold
- Tested at DESY II Test-Beam Facility at about 4 GeV
- Charge calibration with  $^{55}\text{Fe}$
- Data analyzed with Corryvreckan
  - ClusteringAnalog: allows offline threshold scans

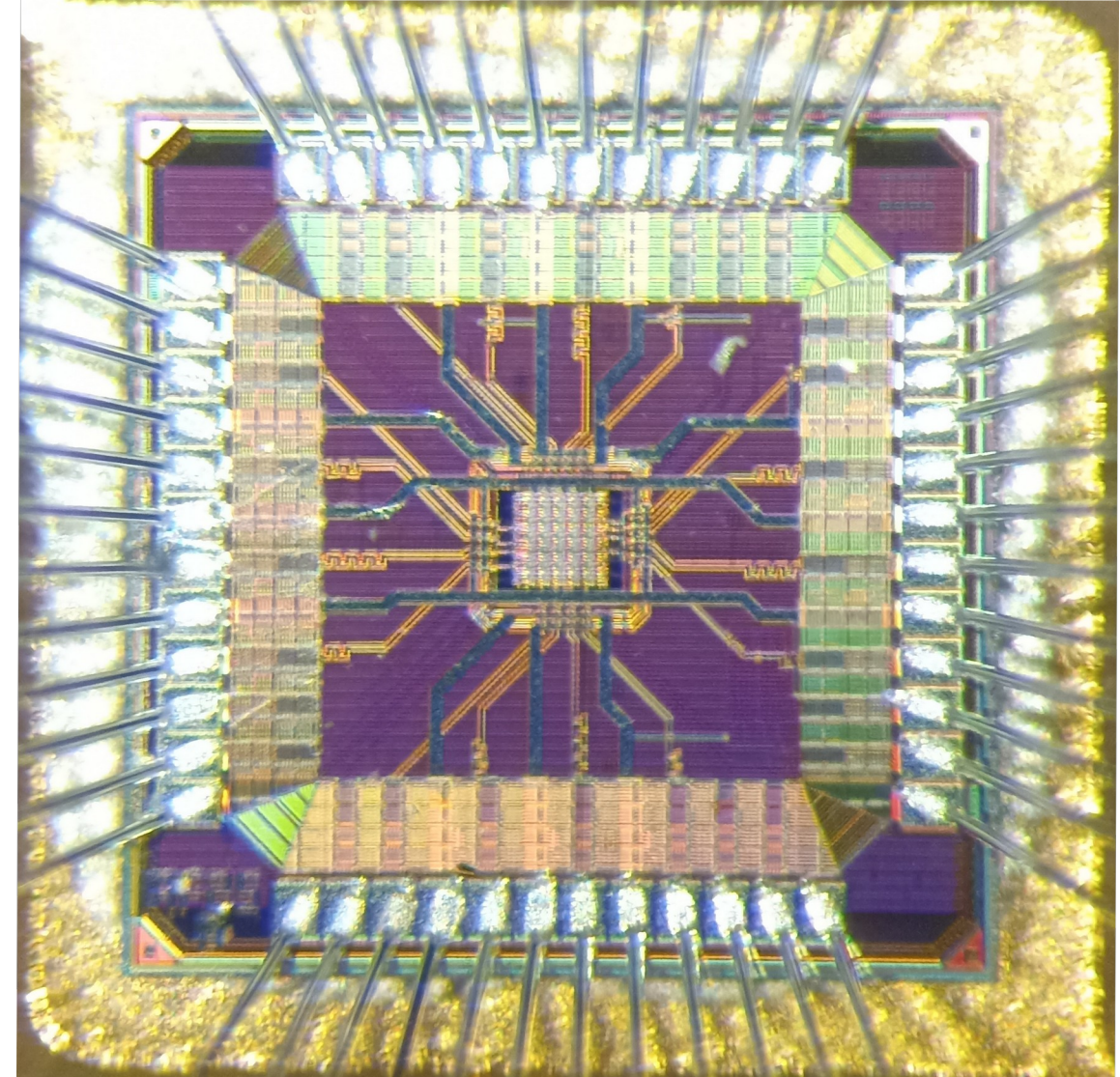
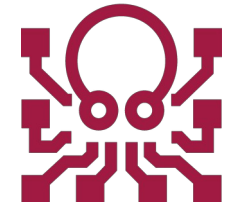


# Selected Conditions

Covering Limited Parameter Range

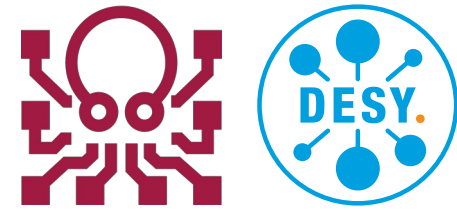
- Use 4.8 V, if available
  - not expecting strong dependence for n-blc
- Noise below 30 electrons
- Use three thresholds if that allows efficient operation

Pitch [ $\mu\text{m}$ ]	Type	Bias [V]	Thresholds [e]
15	std	-4.8	100, (150)
25	std	-4.8	100
25	n-blc	-1.2	100, 150
25	n-gap	-4.8	100, 150, 200



# Tools and Methods

## Extracting Spatial Resolutions and Comments on Systematic



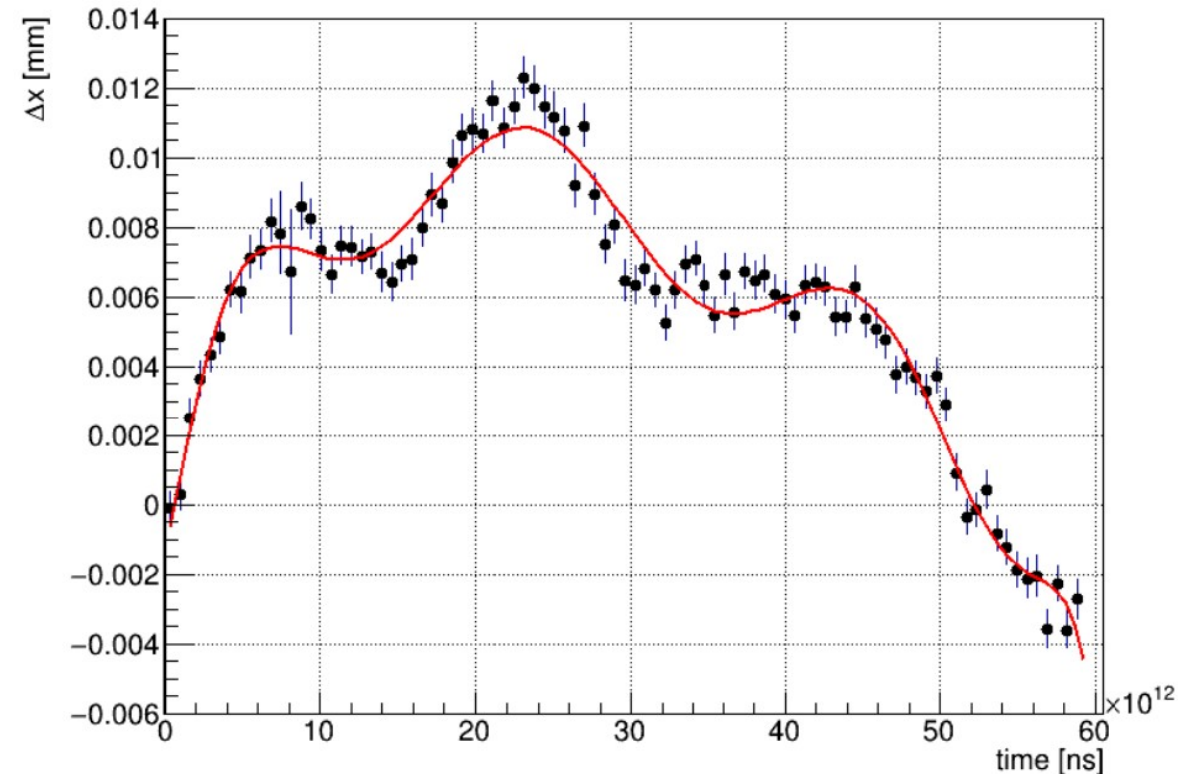
- Characterizing residual width within  $3\sigma$  (RMS in 99.7%)
- Need to subtract track resolution ( $\sigma_{\text{meas}}^2 = \sigma_{\text{tel}}^2 + \sigma_{\text{dut}}^2$ )
- But how to get the track resolution?

### 1) Use the GBL resolution calculator

- Probably underestimates track resolution (time dependence)

### 2) Use a method similar to [\[Antonello\]](#) M2

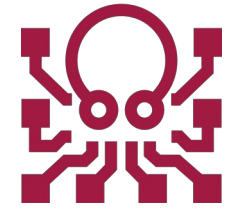
- Cut on  $\text{abs}(\eta) = |(c_l - c_r) / (c_l + c_r)| < 0.1$  and cluster charge  $< 700 e$
- Assume DUT resolution is sub-dominant (checked with simulation)
- Potentially overestimates track resolution



- Alignment depends on time
- Correction based on polynomial fit
- Remaining impact depends on run duration

# Tools and Methods

## Overview Track Resolution



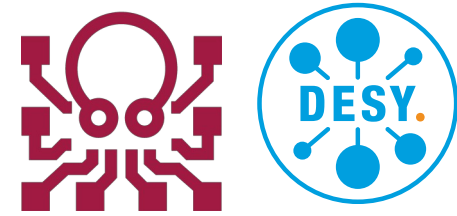
Design	Pitch [um]	Voltage [V]	$\sigma_{\text{track}}$ GBL [um]	$\sigma_{\text{track}}$ M2 [um]
n-gap	25	-4.8	2.5	3.7
		y	2.5	3.4
n-blc	25	-1.2	2.5	4.0
		y	2.5	4.3
std	25	-4.8	2.5	5.0
		y	2.5	4.0
std	15	-4.8	1.9	4.0
		y	1.9	4.4

Consider systematics between runs! Many conclusions can be made within a run, though!

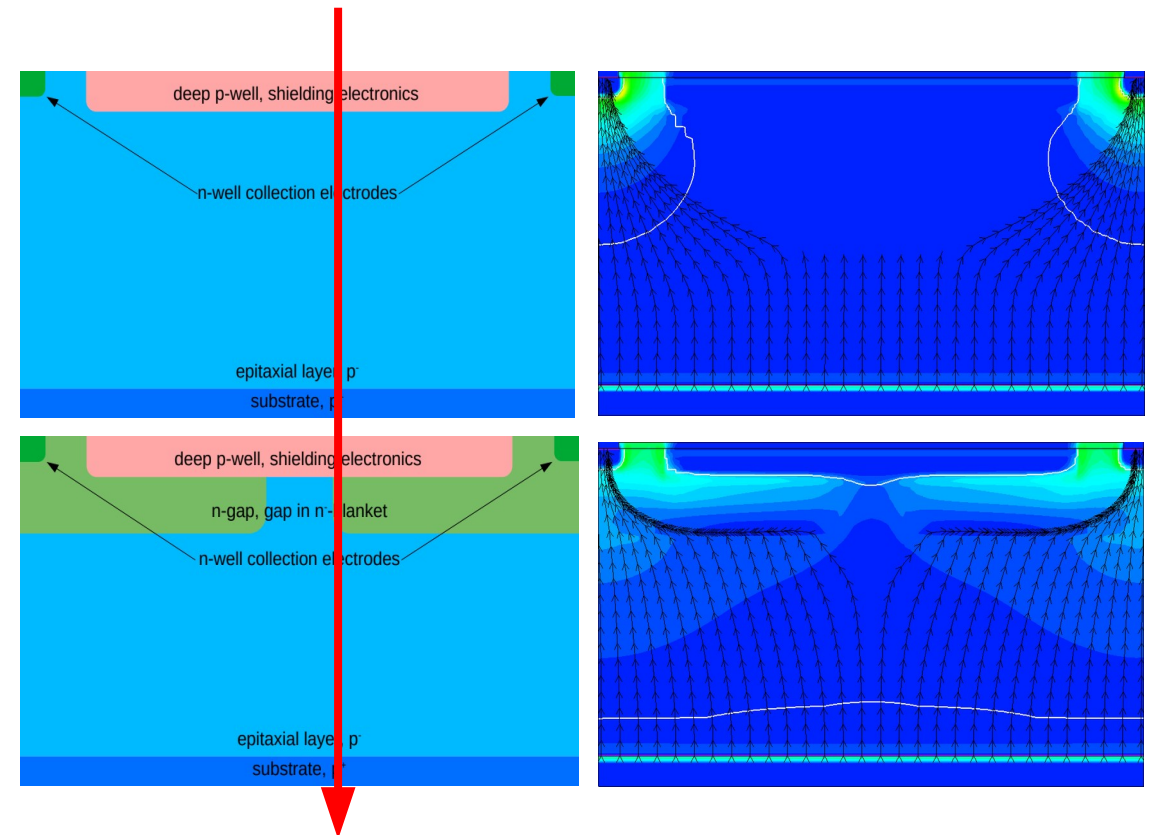
# Motivating

## Eta Correction

- Imagine a particle hitting our detector close to the pixel boundary
- The charge collected in each electrode depends on the electric field
  - Standard layout: low field, diffusion component, charge sharing close to 50-50
  - n-gap layout: larger field, collection by drift, charge sharing close to 0-100
- In both cases, we estimate the particle position using a charge-weighted center of gravity – this is wrong
- It is the job of the eta correction to find out how wrong this is and to correct for the effect

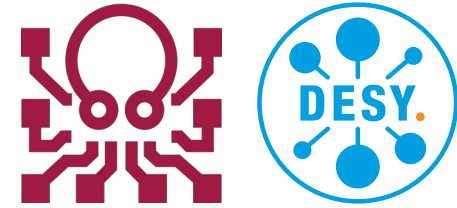


Ionizing particle

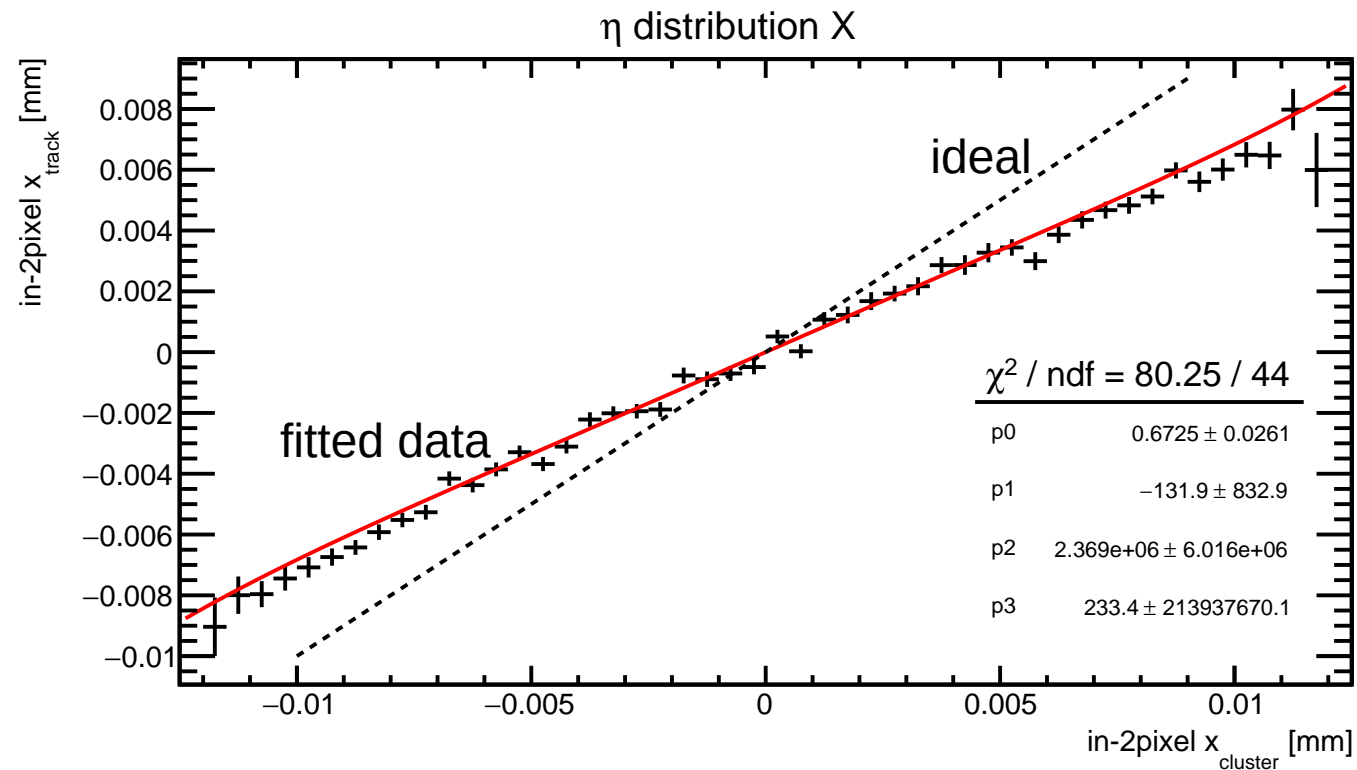


# Tools and Methods

## Correcting Bias of Spatial Residuals – Eta Correction



- Using modules **EtaCalculation** and **EtaCorrection**
- The idea is simple
  - Plot the intercept of an associated track as a function of the reconstructed position (both in-pixel, modulo the pitch)
  - This reveals the bias of the reconstruction (deviation from diagonal)
  - Fit appropriate function (polynomial with 4 odd terms)
  - Use the fit to correct for the bias (in a next iteration over the run)
- Not stable if the number of charge bins is small

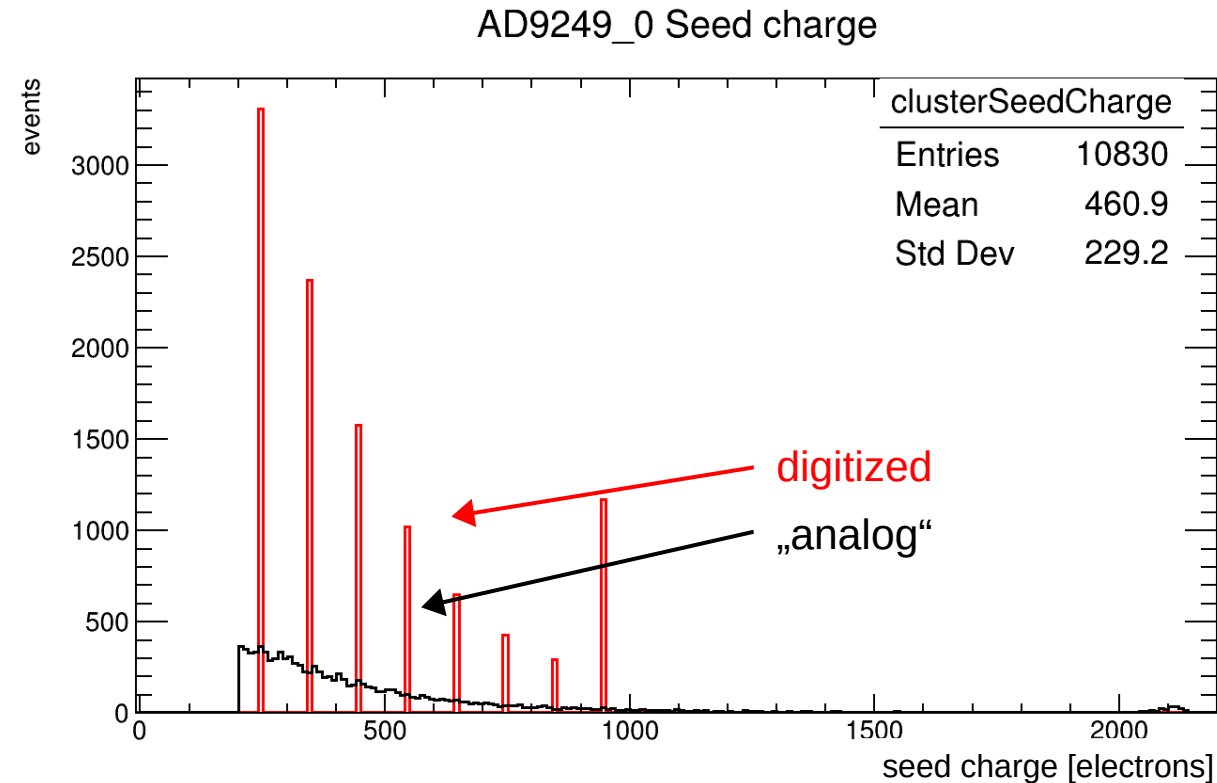
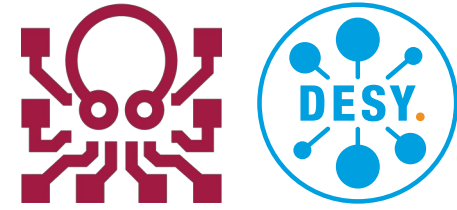


Example, eta correction for n-gap at 100 e

# Tools and Methods

## Offline Digitization

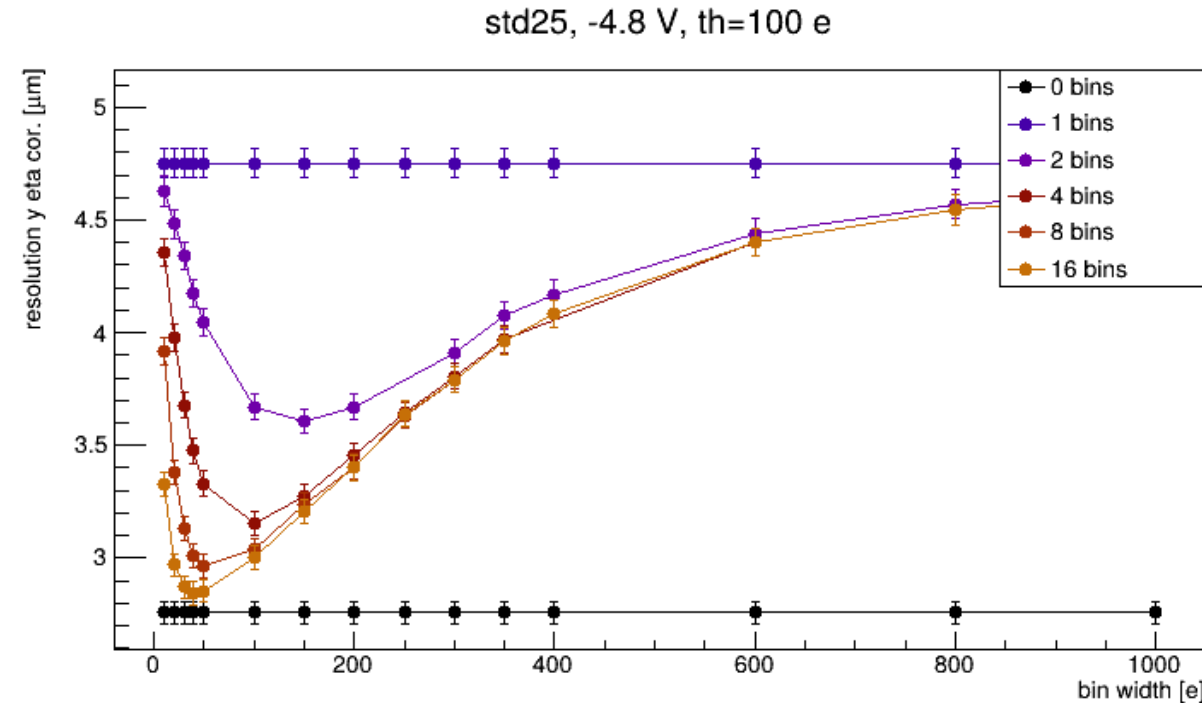
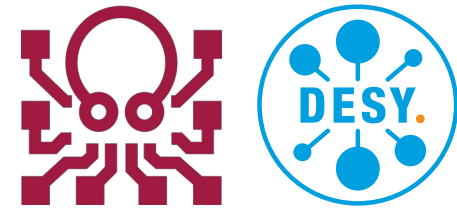
- Our analysis chain makes use of **C**luster**i**ng**A**na**l**og
- This allows easy **offline threshold emulation**
- Added **digitization** feature with two parameters
  - digitizerBinWidth; example 100 e
  - digitizerBinNumber; example 8 bins
- Scanning
  - Bin width from 10 e to 1000 e (increasing step size)
  - Number of bins 0 (analog), 1(binary), 2, 4, 8, 16
- Challenge – need eta-correction for 810 conditions
  - Charge weighting will not yield optimal resolution
  - Need to apply eta correction for all studied cases



# Effect of Digitization Parameters

## An Example

- Straight lines for the extreme cases binary (1 bin) and infinite (0 bins) charge granularity
- The bin width matters
  - Choosing bins too small or too large close to binary
  - Optimal when the dynamic range covers ~50% of the MPV
- „Two threshold” approach (1 bin)
  - Levers 50% of the achievable improvement
- Eta-correction makes little difference
  - Either linear charge sharing or small cluster size

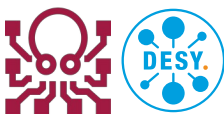


# Results

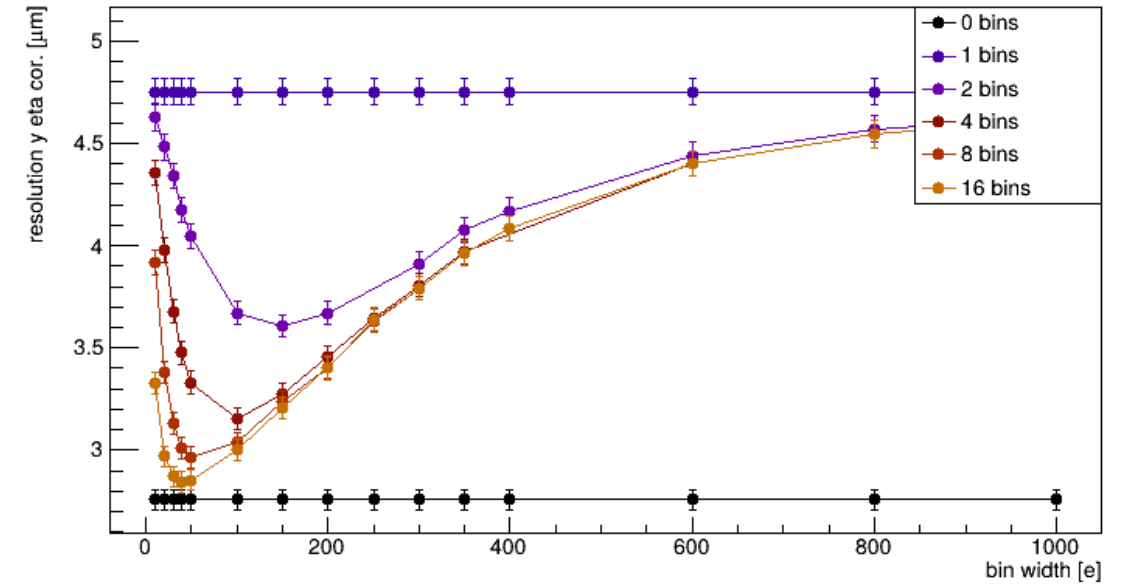
## Low Thresholds

This is interesting!

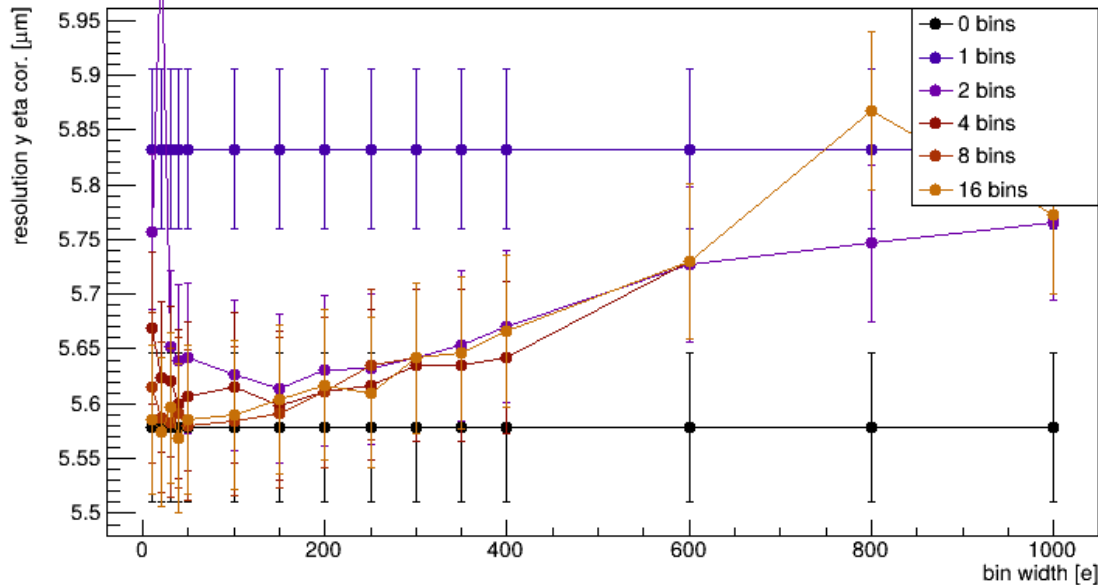
- Profit from charge info,  $\text{std} > \text{blc} > \text{gap}$
- Two bins enough to get  $> 50\%$  of the potential



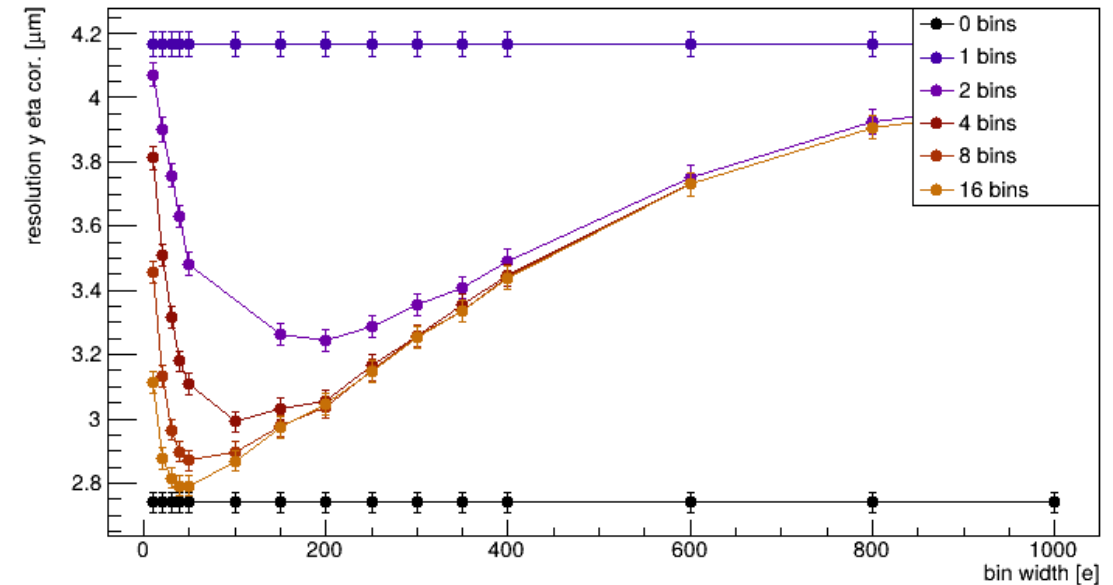
std25, -4.8 V, th=100 e



n-gap25, -4.8 V, th=100 e



n-blc25, -1.2 V, th=100 e

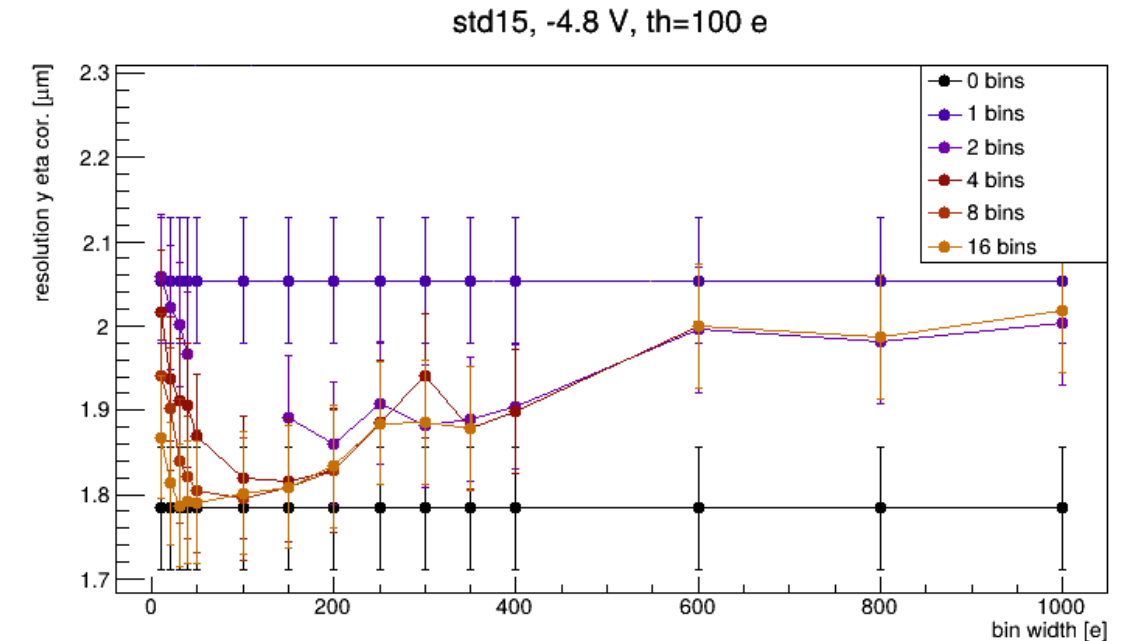
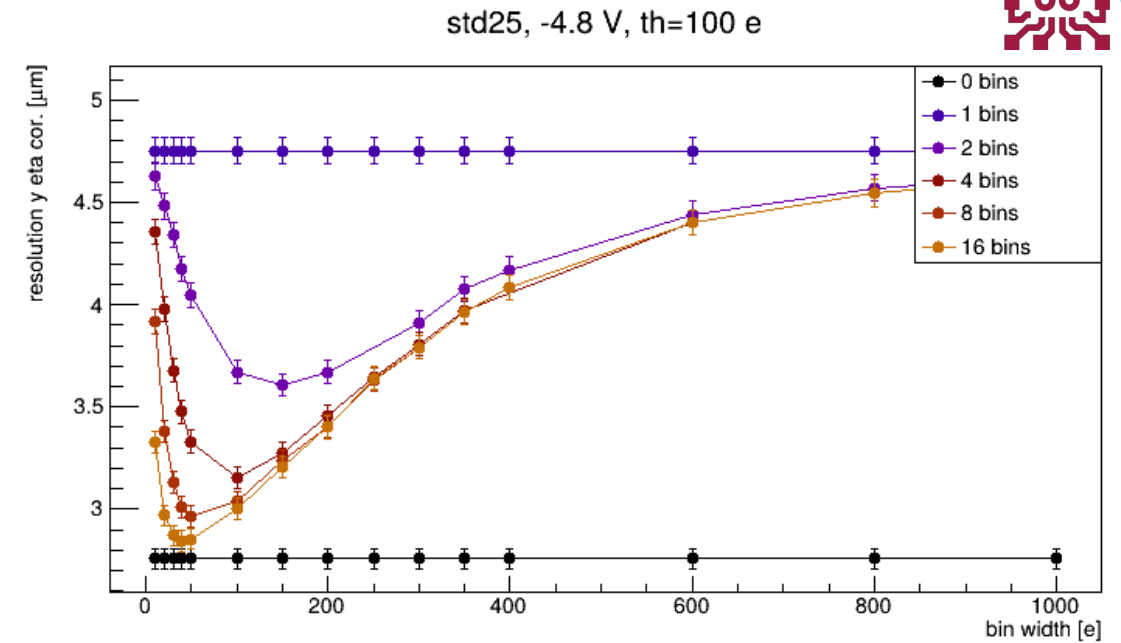
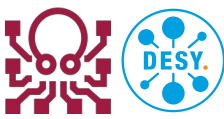


# Results

## Comparing Pitch

This is interesting!

- Profit from charge info,  $\text{std} > \text{blc} > \text{gap}$
- Two bins enough to get  $> 50\%$  of the potential
- The effect of the charge info reduces with
  - Decreasing pitch  
(limited by noise?)

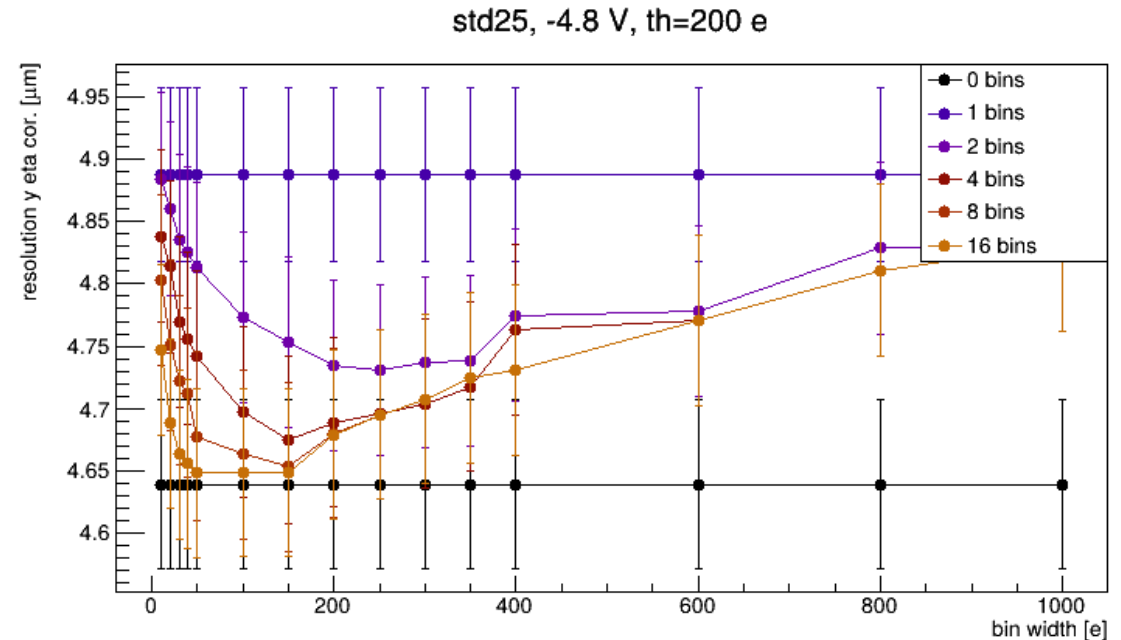
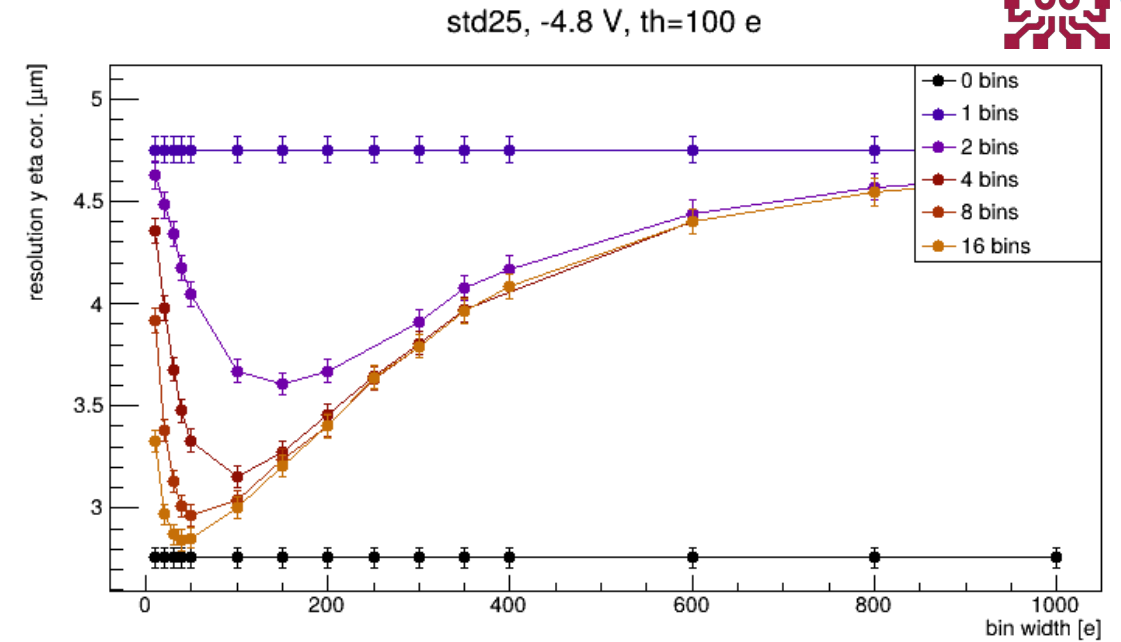
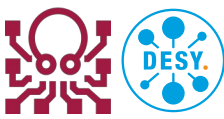


# Results

## Comparing Thresholds

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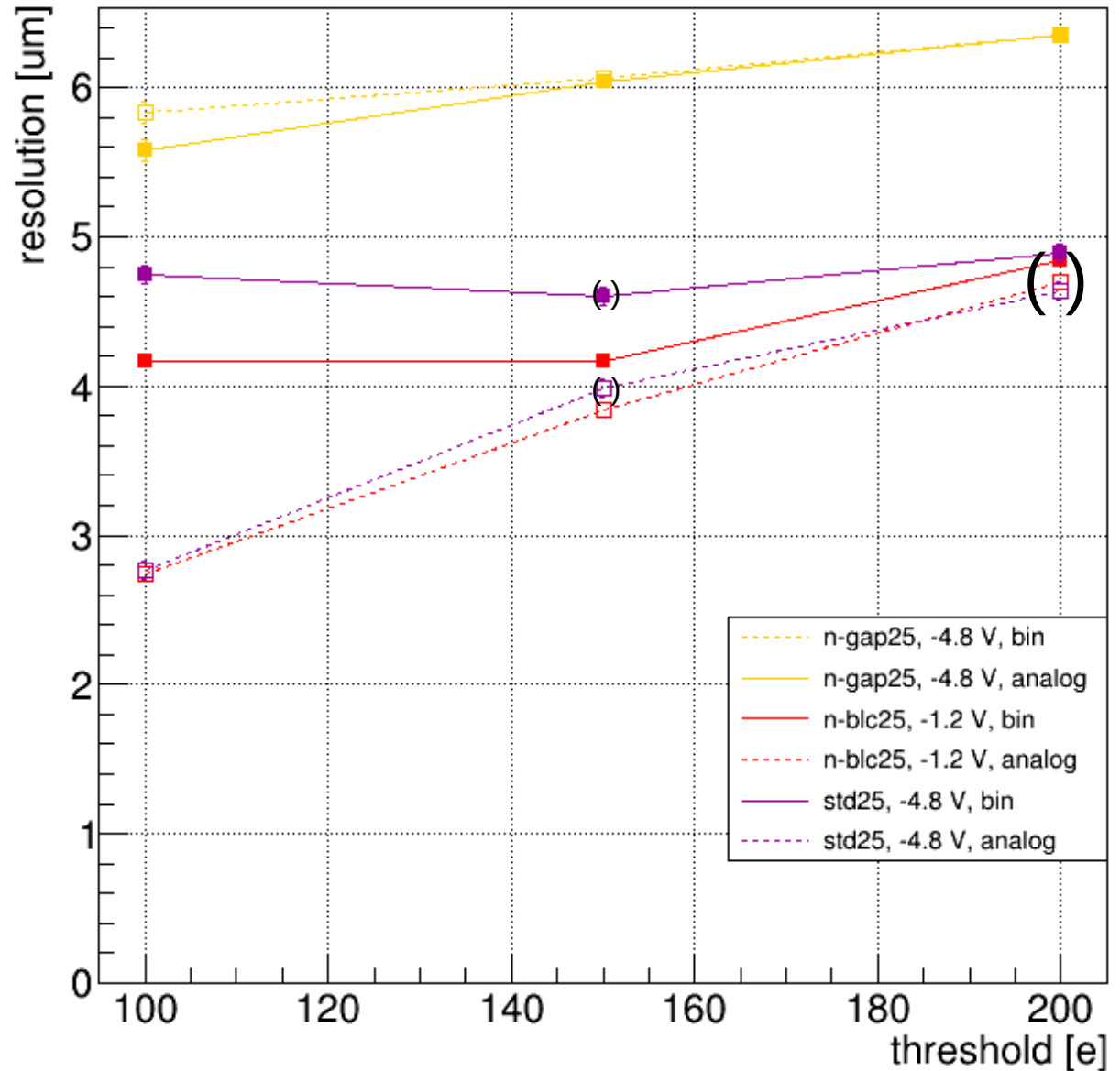
- Profit from charge info,  $\text{std} > \text{blc} > \text{gap}$
- Two bins enough to get  $> 50\%$  of the potential
- The effect of the charge info reduces with
  - Decreasing pitch  
(limited by noise?)
  - Increasing threshold  
cluster size (efficiency) decreases



# Results

## Threshold Dependence

- Caveats
  - Points in () are below 99% efficiency
  - Systematic uncertainties between designs (telescope resolution)
- Threshold has comparably large impact
  - n-gap: resolution gains from threshold larger than resolution gains from charge info
  - n-blanket and standard: need low threshold to profit from charge info



# Results

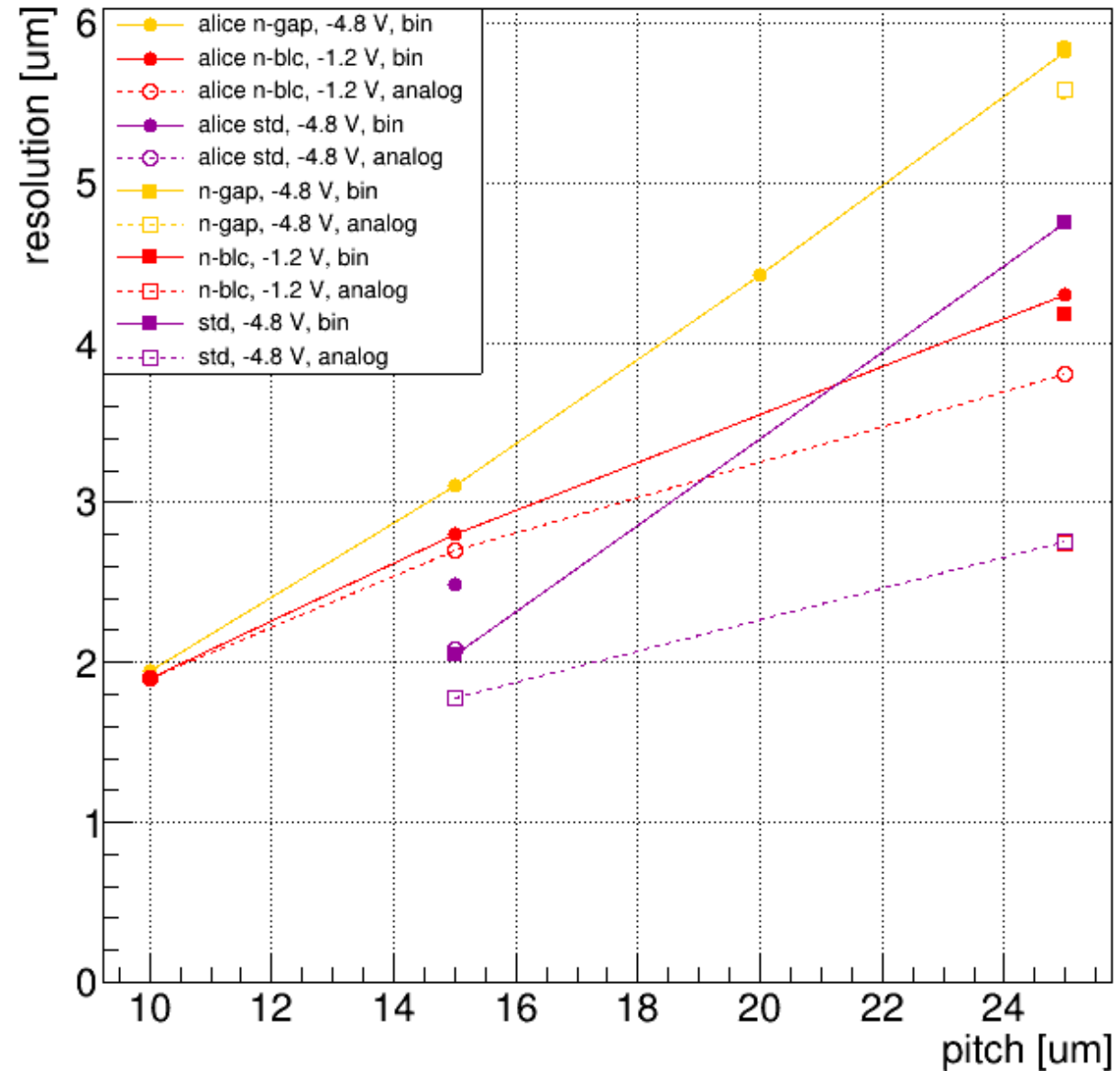
## Pitch Dependence

- Alice data is from APTS [\[ref. pub.\]](#)
  - Pitch has clear, strong, linear impact on spatial resolution for n-gap and n-blanket design
  - Alice results indicate lower impact of charge info
    - Especially n-blanket 25  $\mu\text{m}$
- Data for standard layout is a bit scarce/ confusing
  - 15  $\mu\text{m}$ : small tension between Alice and us
  - 25  $\mu\text{m}$ , binary: this is unexpectedly bad

### To achieve a resolution better than 3 $\mu\text{m}$ :

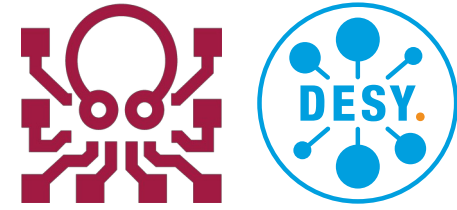
- Pitch and design are crucial, threshold too
- Impact of charge info might make difference

100 e threshold



# The Answers

## To Shape the Design of a Pixel Sensor for a Future Lepton Collider



Key questions concerning spatial resolution

- What are the limits achievable with a certain design (standard, n-blanket, n-gap)?
- How do these limits depend on the pixel pitch and threshold?

→ Campaign of simulations and literature review within OCTOPUS

} Anastasias talk

→ Pitch has a lower limit from design constrains!

} Robertos talk

- How much potential for improvements does charge information offer?

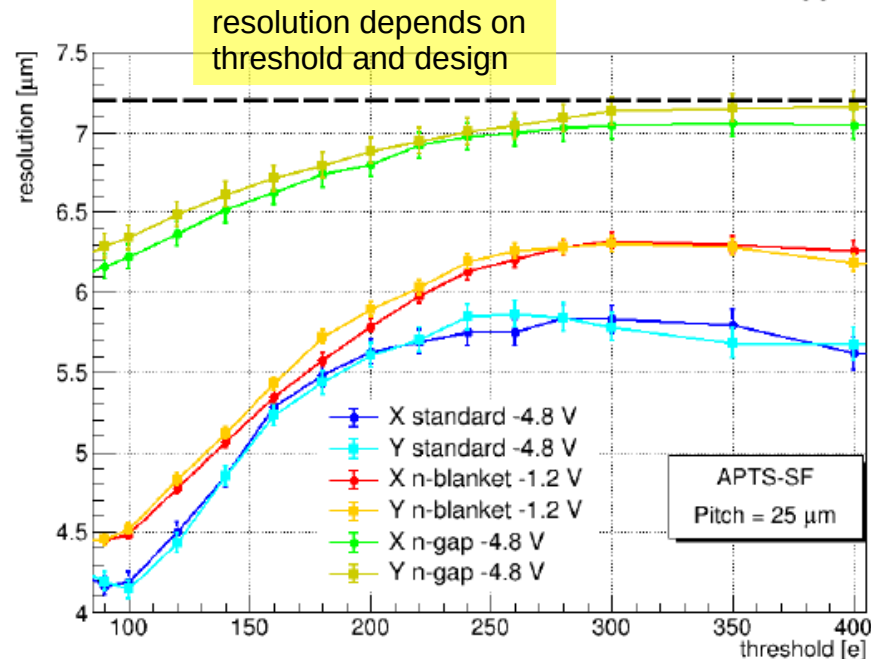
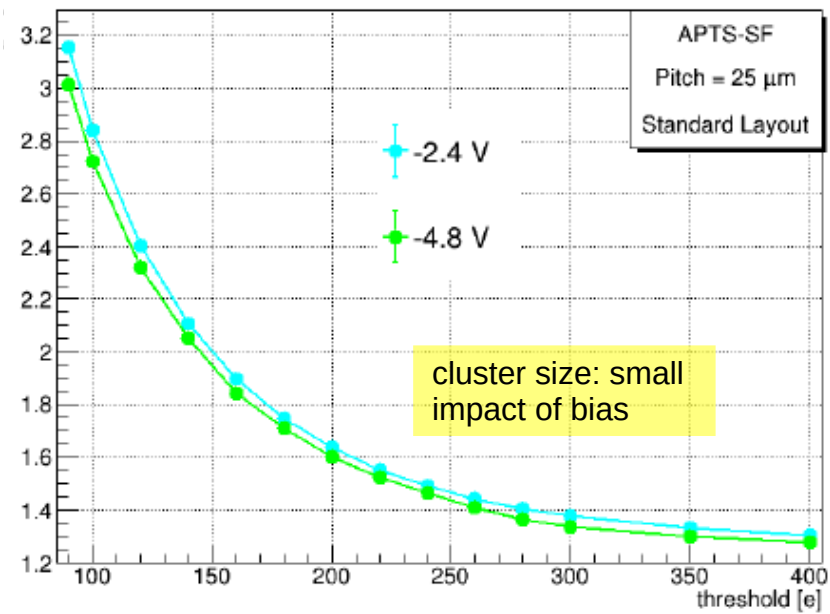
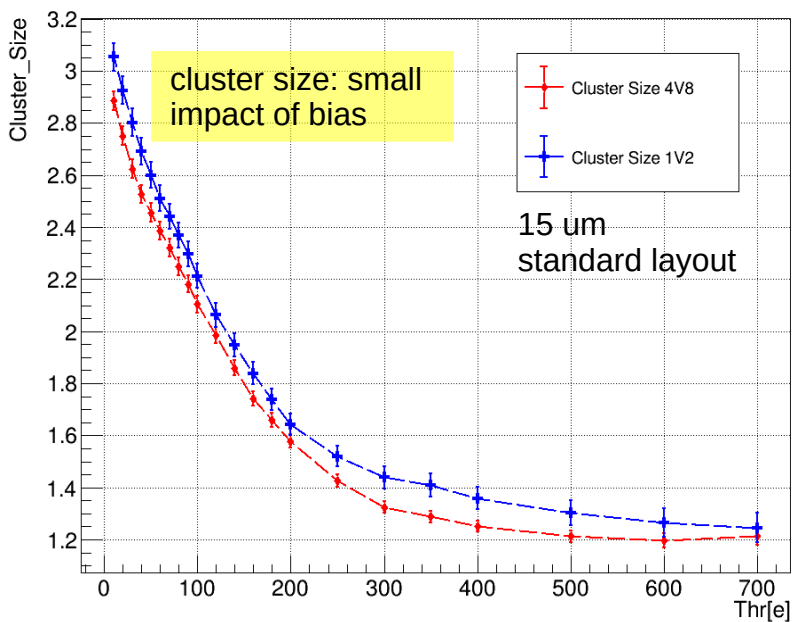
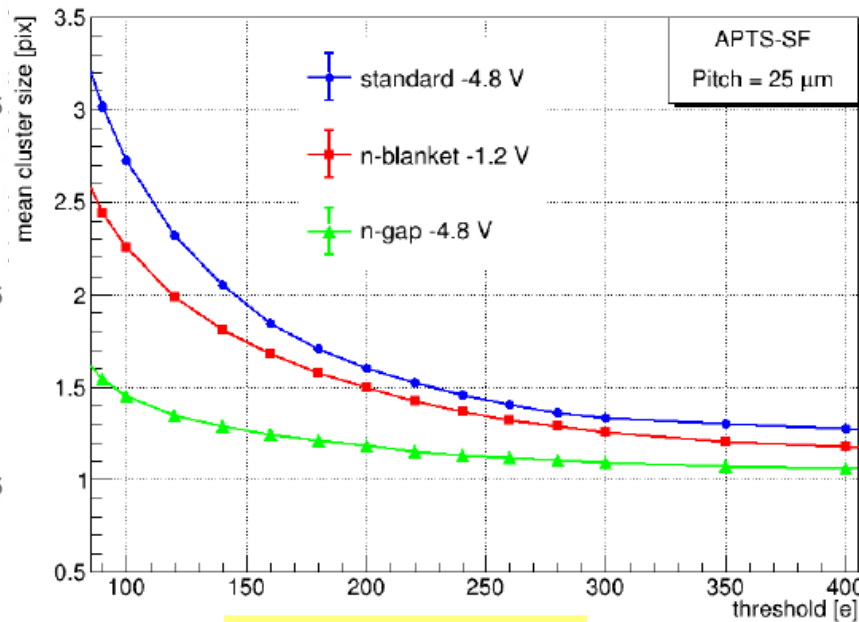
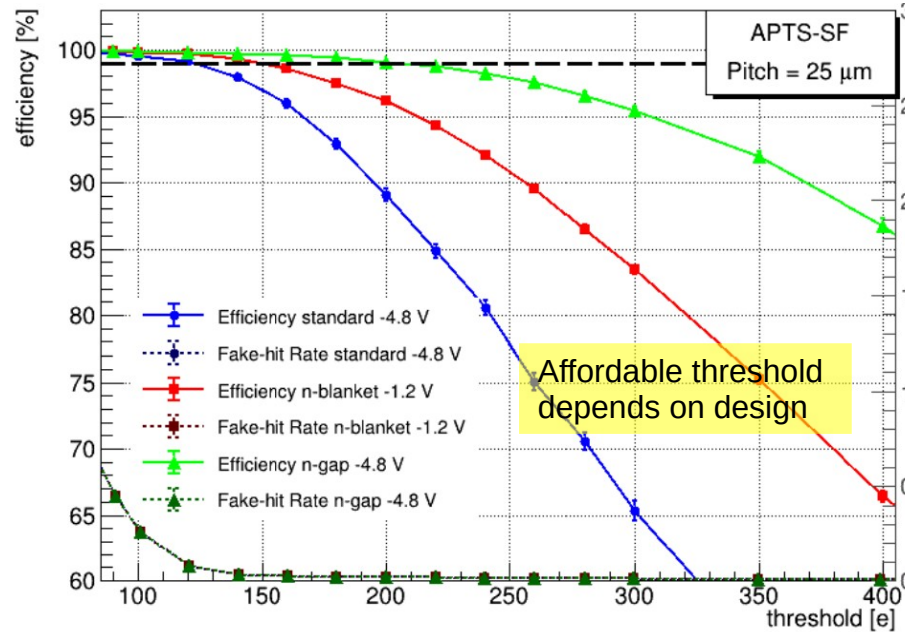
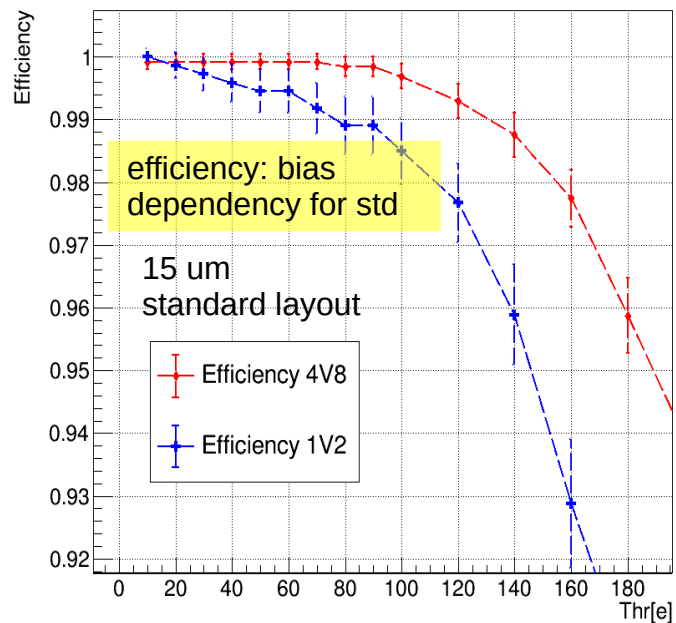
- How many bits do we need in order to leverage this potential?
- What about two thresholds?

→ Spatial resolution profits most from “the first 2 bits”

→ Temporal resolution drives the requirement on charge granularity

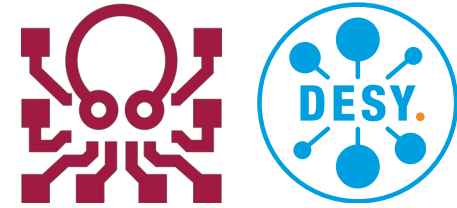
} Robertos talk



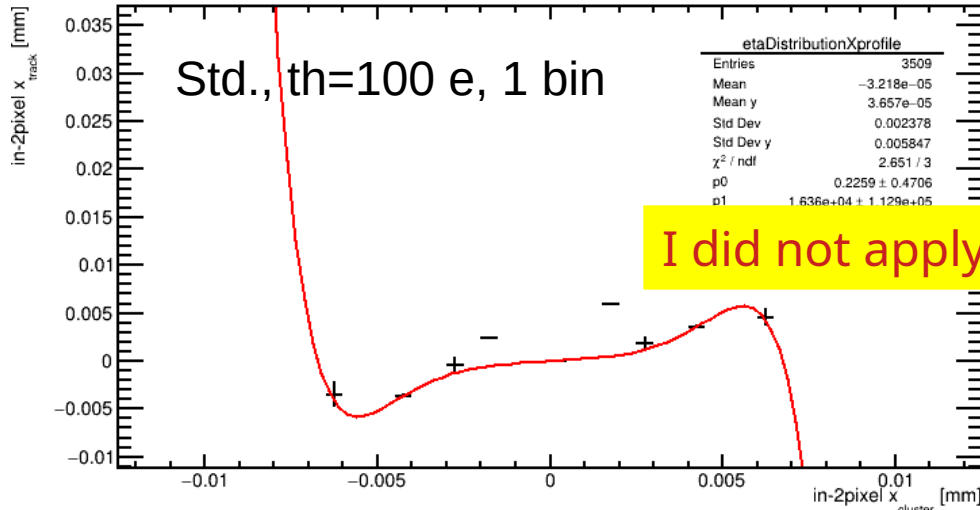


# Tools and Methods

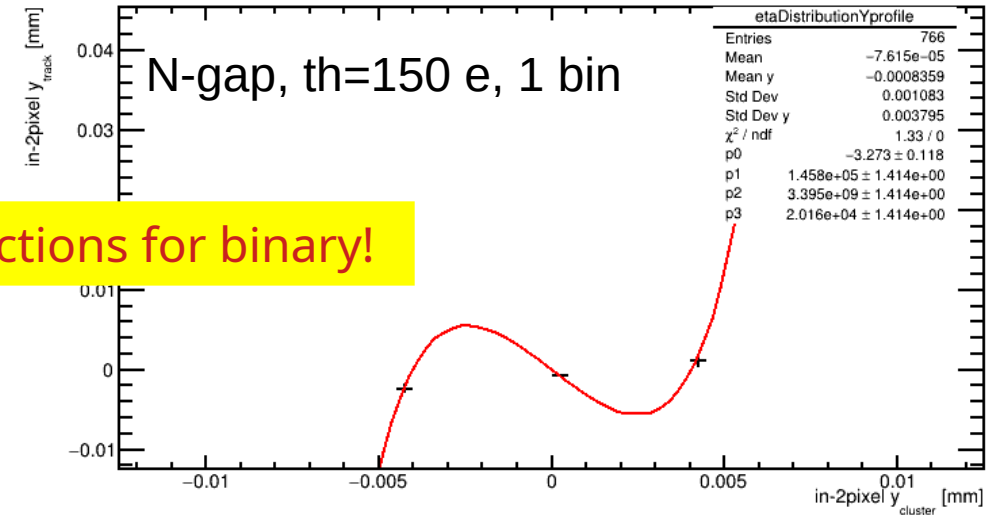
## Eta Correction - Examples



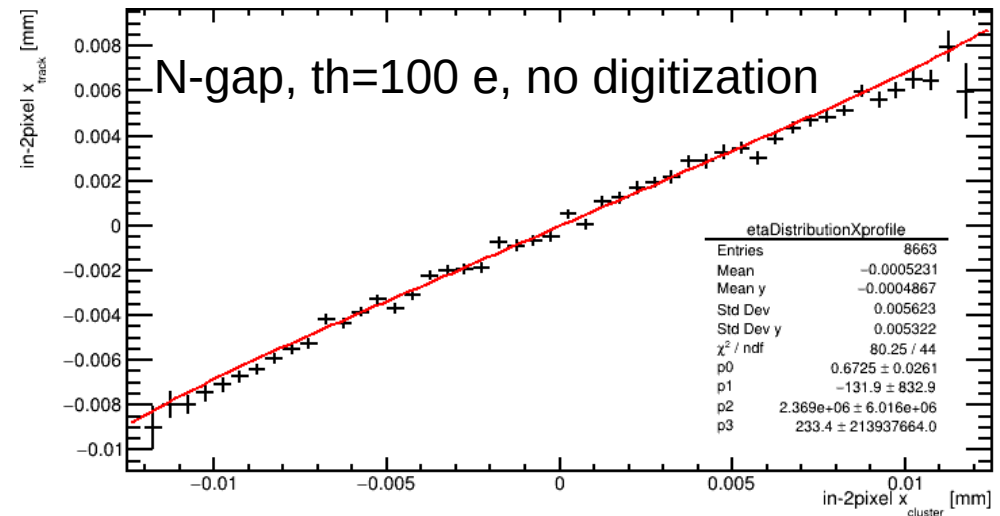
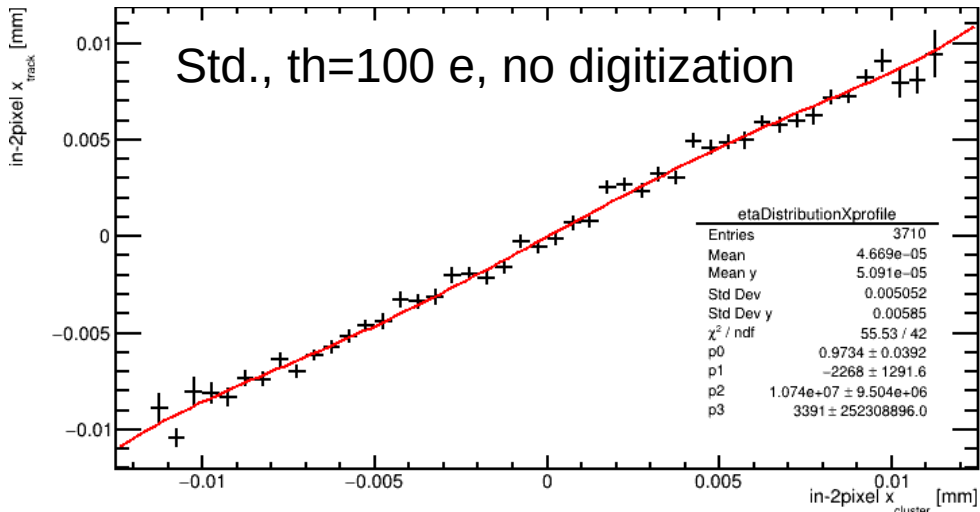
$\eta$  distribution X



$\eta$  distribution Y



I did not apply eta-corrections for binary!

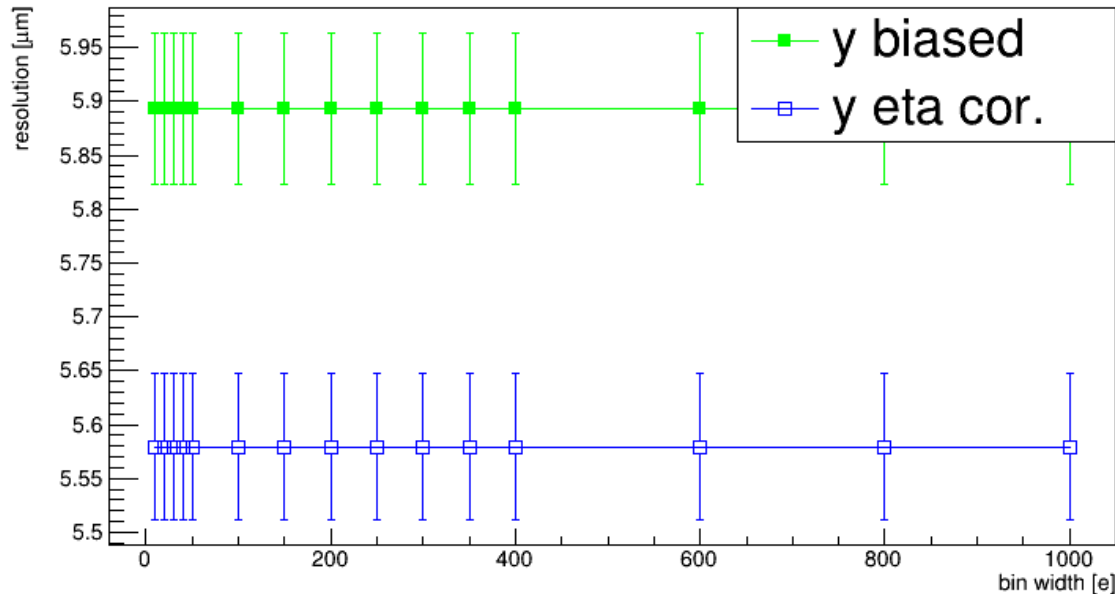


# The „Eta-Potential“

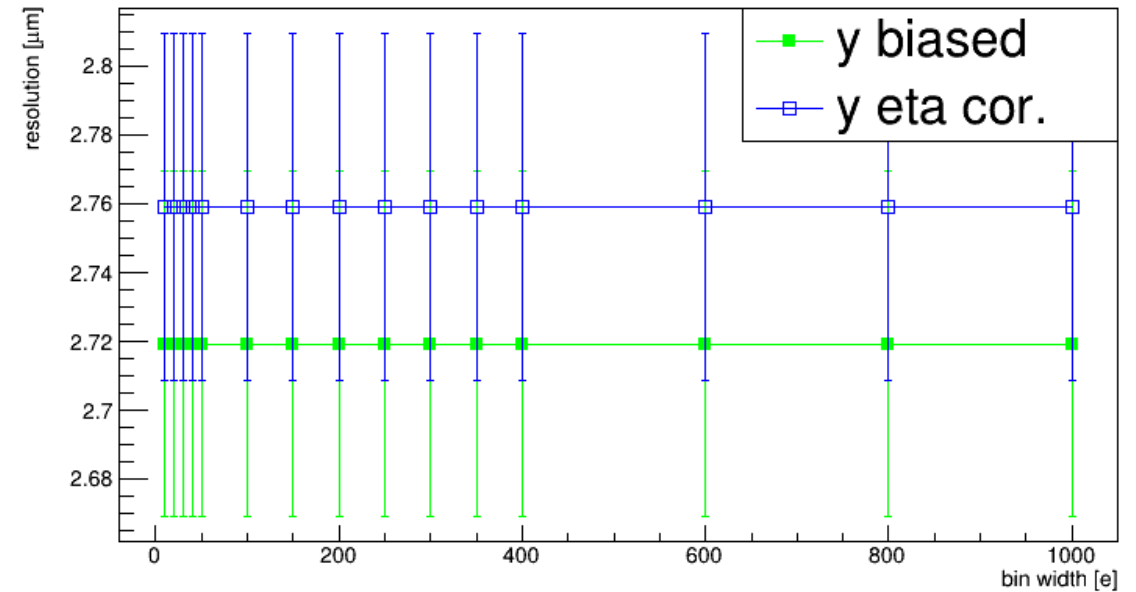
How much can we gain from the Eta-Correction?\*

- Especially at low thresholds
- Overall not that impressive
  - Either small cluster size (n-gap)
  - Or relatively linear charge sharing (std)
- However, this does not mean that charge info is

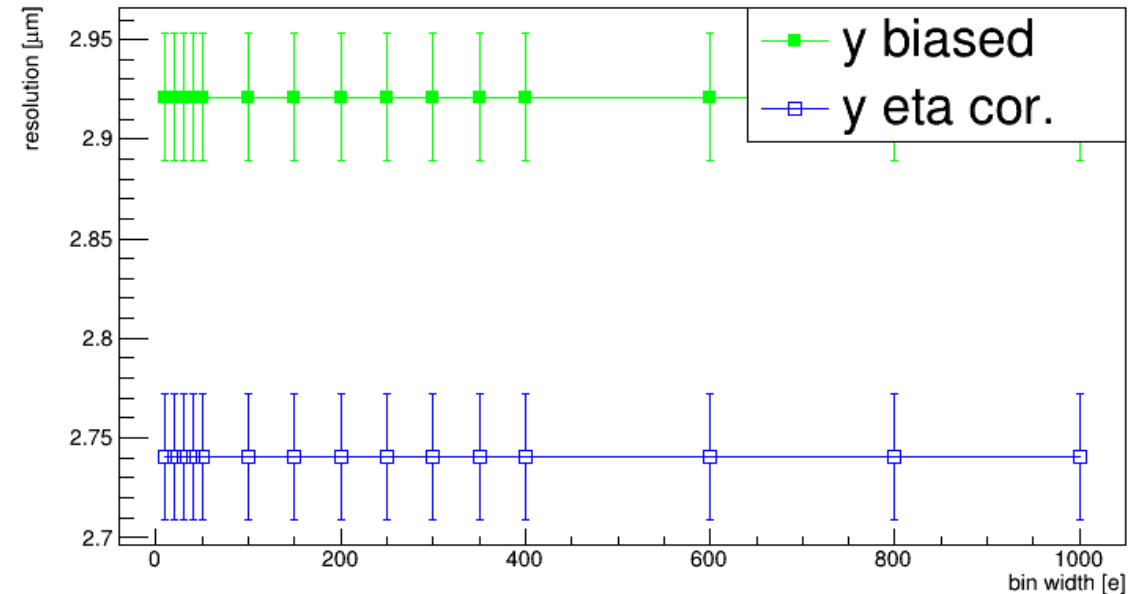
n-gap25, -4.8 V, th=100 e, 0 bins



std25, -4.8 V, th=100 e, 0 bins



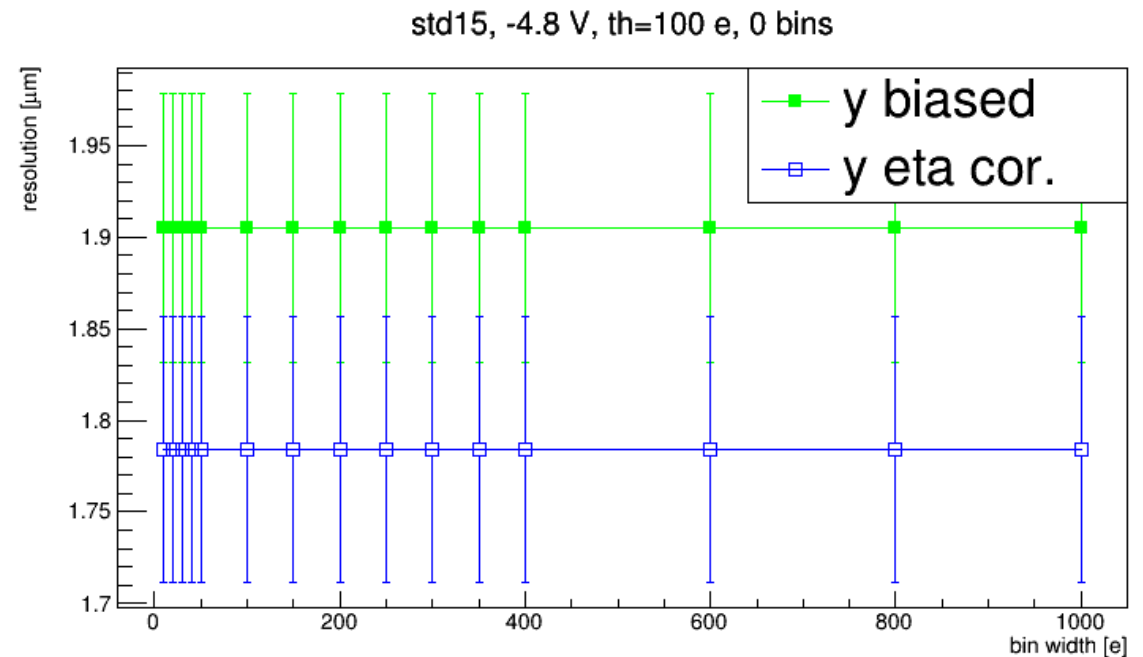
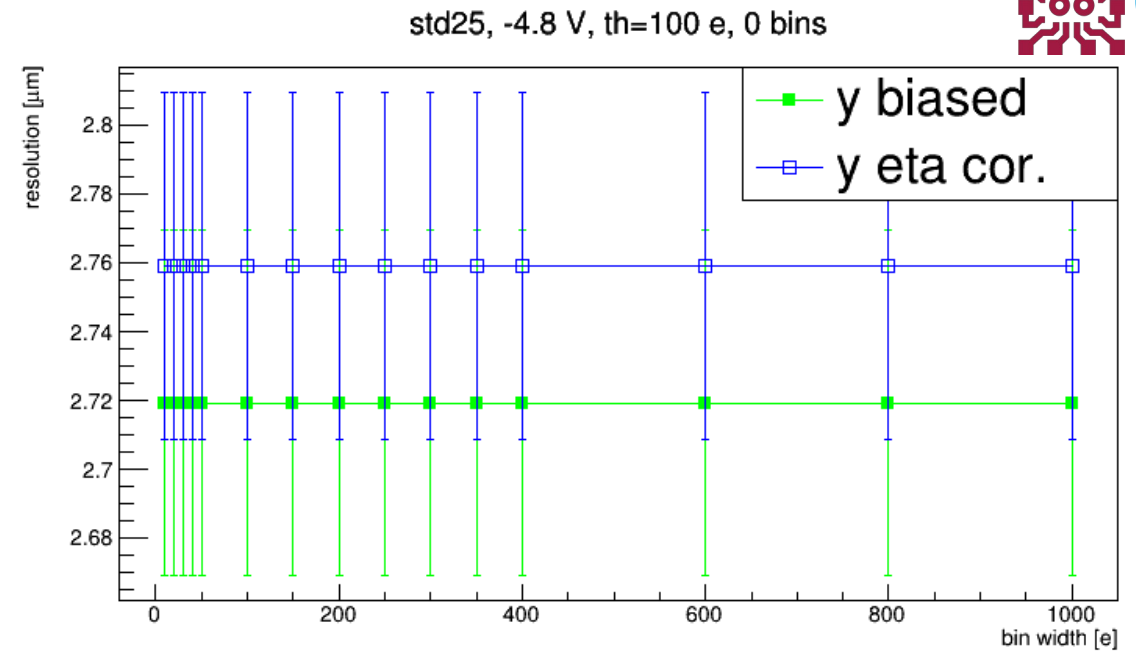
n-blc25, -1.2 V, th=100 e, 0 bins



# The „Eta-Potential“

How much can we gain from the Eta-Correction?\*

- Especially at low thresholds
- Overall not that impressive
  - Either small cluster size (n-gap)
  - Or relatively linear charge sharing (std)
- However, this does not mean that charge info is useless!





## Contact

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Tangerine

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